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CONTENTS

15 NOVEMBER 2001-I

Announcement: Electronic-First Publication and Article Numbers i

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Variational finite-difference representation of the kinetic energy operator (4 pages) 193101
P. Maragakis, José Soler, and Efthimios Kaxiras
- Quantum Monte Carlo calculation of the finite temperature Mott-Hubbard transition (4 pages) 193102
Jaewook Joo and Viktor Oudovenko
- Probability distribution of the conductance in anisotropic systems (4 pages) 193103
Marc Rühländer, Peter Markoš, and C. M. Soukoulis

Semiconductors I: bulk

- Femtosecond transient absorption study of oriented poly(9,9-dioctylfluorene) film: Hot carriers, excitons, and charged polarons (4 pages) 193201
S. Xu, V. I. Klimov, B. Kraabel, H. Wang, and D. W. McBranch
- Ab initio* determination of the atomistic structure of $\text{Si}_x\text{Ge}_{1-x}$ alloy (4 pages) 193202
P. Venezuela, G. M. Dalpian, Antônio J. R. da Silva, and A. Fazzio

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- Analysis of InAs(001) surfaces by reflectance anisotropy spectroscopy (4 pages) 193301
C. Goletti, F. Arciprete, S. Almagia, P. Chiaradia, N. Esser, and W. Richter
- Signatures of the discrete level spectrum in temperature-dependent transport through open quantum-dot arrays (4 pages) 193302
A. Shailos, C. Prasad, M. Elhassan, R. Akis, D. K. Ferry, J. P. Bird, N. Aoki, L.-H. Lin, Y. Ochiai, K. Ishibashi, and Y. Aoyagi
- Role of defects in the electronic properties of amorphous/crystalline Si interface (4 pages) 193303
Maria Peressi, Luciano Colombo, and Stefano de Gironcoli
- Tuning a resonance in Fock space: Optimization of phonon emission in a resonant-tunneling device (4 pages) 193304
L. E. F. Foa Torres, H. M. Pastawski, and S. S. Makler
- Stability of the fractional quantum Hall effect in higher Landau levels for composite fermions carrying four vortices (4 pages) 193305
T. Sbeouelji and N. Meskini
- Fast incomplete decoherence of nuclear spins in a quantum Hall ferromagnet (4 pages) 193306
T. Maniv, Yu. A. Bychkov, I. D. Vagner, and P. Wyder



Coulomb Luttinger liquid (<i>4 pages</i>)	193307
D. W. Wang, A. J. Millis, and S. Das Sarma	
Dynamical theory for modeling dipole-dipole interactions in a microcavity: The Green dyadic approach (<i>4 pages</i>)	193308
R. L. Hartman and P. T. Leung	
Role of doped layers in the dephasing of two-dimensional electrons in quantum-well structures (<i>4 pages</i>)	193309
G. M. Minkov, A. V. Germanenko, O. E. Rut, A. A. Sherstobitov, B. N. Zvonkov, E. A. Uskova, and A. A. Birukov	
Te covered Si(001): A variable surface reconstruction (<i>4 pages</i>)	193310
Prasenjit Sen, S. Ciraci, Inder P. Batra, and C. H. Grein	
Segregation-enhanced etching of Cd during Zn deposition on CdSe quantum dots (<i>4 pages</i>)	193311
T. Passow, H. Heinke, T. Schmidt, J. Falta, A. Stockmann, H. Selke, P. L. Ryder, K. Leonardi, and D. Hommel	
Light-induced metallization at the gallium-silica interface (<i>4 pages</i>)	193312
P. Petropoulos, H. S. Kim, D. J. Richardson, V. A. Fedotov, and N. I. Zheludev	
Initial adsorption configurations of acetylene molecules on the Si(001) surface (<i>4 pages</i>)	193313
Wondong Kim, Hanchul Kim, Geunseop Lee, Young-Kyu Hong, Kidong Lee, Chanyong Hwang, Dal-Hyun Kim, and Ja-Yong Koo	
Molecular dynamics simulations of solid-phase epitaxy of Si: Defect formation processes (<i>4 pages</i>)	193314
Shinji Munetoh, Koji Moriguchi, Akira Shintani, Ken Nishihira, and Teruaki Motooka	
Coulomb staircase and Wigner crystalline states in single-electron tunneling through one-dimensional arrays (<i>4 pages</i>)	193315
M. Stopa	
Bound states of L- or T-shaped quantum wires in inhomogeneous magnetic fields (<i>4 pages</i>)	193316
Yuh-Kae Lin, Yueh-Nan Chen, and Der-San Chuu	
Surface physics, low-dimensional systems, and related topics	
Extreme hydrogen sensitivity of the transport properties of single-wall carbon-nanotube capsules (<i>4 pages</i>)	193401
Antonis N. Andriotis, Madhu Menon, Deepak Srivastava, and George Froudakis	
Electron-phonon coupling and optical transitions for indirect-gap semiconductor nanocrystals (<i>4 pages</i>)	193402
C. Delerue, G. Allan, and M. Lannoo	
Charge state of medium-energy He ions after large-angle single collisions (<i>3 pages</i>)	193403
Y. Kido, T. Nishimura, Y. Hoshino, E. Toyoda, and T. Nakada	
Role of symmetry on interface states in magnetic tunnel junctions (<i>4 pages</i>)	193404
C. Uiberacker and P. M. Levy	
Crossover in energy redistribution during $C_{60}@Xe_{144}$ surface impact (<i>4 pages</i>)	193405
Mao-Hua Du and Hai-Ping Cheng	
Structure gap in heterogeneous catalysis: Kinetic aspects (<i>4 pages</i>)	193406
V. P. Zhdanov	
Correlated quantum measurement of a solid-state qubit (<i>4 pages</i>)	193407
Alexander N. Korotkov	
Electron confinement in nickel and copper nanostructures on Cu(111) (<i>4 pages</i>)	193408
Stéphane Pons, Pierre Mallet, and Jean-Yves Veuillen	
Carbon foam: Spanning the phase space between graphite and diamond (<i>3 pages</i>)	193409
Koichiro Umemoto, Susumu Saito, Savas Berber, and David Tománek	
Order-disorder character of the (3×3) to $(\sqrt{3} \times \sqrt{3})R30^\circ$ phase transition of Sn on Ge(111) (<i>4 pages</i>)	193410
L. Petaccia, L. Floreano, A. Goldoni, D. Cvetko, A. Morgante, L. Grill, A. Verdini, G. Comelli, G. Paolucci, and S. Modesti	

Tip-surface forces, amplitude, and energy dissipation in amplitude-modulation (tapping mode) force microscopy (4 pages)	193411
Alvaro San Paulo and Ricardo García	
Resonant surface second harmonic generation from Au films on NaCl(100) (4 pages)	193412
T. Kitahara, H. Tanaka, Y. Nishioka, and G. Mizutani	
Melting and orientational order of the screened Wigner crystal on helium films (4 pages)	193413
Paulo S. Branício, José-Pedro Rino, and Nelson Studart	

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Effect of structural disorder on the Urbach energy in Cu ternaries (8 pages)	195101
S. M. Wasim, C. Rincón, G. Marín, P. Bocaranda, E. Hernández, Ismarido Bonalde, and Ernesto Medina	
Electronic structure of the sodium and potassium electrosodalites (Na/K) ₈ (AlSiO ₄) ₆ (6 pages)	195102
Georg K. H. Madsen, Bo B. Iversen, Peter Blaha, and Karlheinz Schwarz	
Further developments in the local-orbital density-functional-theory tight-binding method (10 pages)	195103
James P. Lewis, Kurt R. Glaesemann, Gregory A. Voth, Jürgen Fritsch, Alexander A. Demkov, José Ortega, and Otto F. Sankey	
Analytical approach to the linear $E \otimes e$ Jahn-Teller problem (12 pages)	195104
Janette L. Dunn and Mark R. Eccles	
Screened-interaction expansion for the Hubbard model and determination of the quantum Monte Carlo Fermi surface (9 pages)	195105
Gökhan Esirgen, Heinz-Bernd Schüttler, Carsten Gröber, and Hans Gerd Evertz	
Transport properties of the Ce _x La _{1-x} Cu _{2.05} Si ₂ heavy-fermion alloy system (12 pages)	195106
M. Očko, D. Drobac, B. Buschinger, C. Geibel, and F. Steglich	
Transport properties of Ce _x Y _{1-x} Cu _{2.05} Si ₂ : A heavy-fermion alloy system on the border of valence fluctuation (7 pages)	195107
M. Očko, C. Geibel, and F. Steglich	
Dopant-host relationships in rare-earth oxides and garnets doped with trivalent rare-earth ions (8 pages)	195108
Elisabeth Antic-Fidancev, Jorma Hölsä, Mika Lastusaari, and Aurelia Lupei	
Quantum theory of a nematic Fermi fluid (6 pages)	195109
Vadim Oganesyan, Steven A. Kivelson, and Eduardo Fradkin	
Efficient recursion method for inverting an overlap matrix (7 pages)	195110
T. Ozaki	
Energy structure of KTaO ₃ and KTaO ₃ :Li (6 pages)	195111
I. I. Tupitsyn, A. Deineka, V. A. Trepakov, L. Jastrabik, and S. E. Kapghan	
High-pressure luminescence studies in Ce ³⁺ :Lu ₂ SiO ₅ (6 pages)	195112
Ulises R. Rodriguez-Mendoza, Garry B. Cunningham, Yongrong Shen, and Kevin L. Bray	
Photonic band gaps, defect characteristics, and waveguiding in two-dimensional disordered dielectric and metallic photonic crystals (7 pages)	195113
Mehmet Bayindir, E. Cubukcu, I. Bulu, T. Tut, E. Ozbay, and C. M. Soukoulis	
Effect of strong correlations and static diagonal disorder in the $d=\infty$ Hubbard model (7 pages)	195114
M. S. Laad, L. Craco, and E. Müller-Hartmann	
Transferable tight-binding model for palladium and silver (11 pages)	195115
Yuannan Xie and John A. Blackman	
Screening of a positron in an inhomogeneous electron gas (14 pages)	195116
H. Stachowiak and E. Boroński	
Spin-entropy-driven melting of the charge order in La _{1.5} Sr _{0.5} CoO ₄ (4 pages)	195117
I. A. Zaliznyak, J. M. Tranquada, R. Erwin, and Y. Moritomo	

Charge density wave-assisted tunneling between Hall edge states (7 pages)	195118
L. Moriconi	
Real-space solution of the coherent potential approximation equations in the Shiba approximation (16 pages)	195119
J. P. Julien, P. E. A. Turchi, and D. Mayou	
Molecular tests of the random phase approximation to the exchange-correlation energy functional (8 pages)	195120
Filipp Furche	
Fermion hypernetted chain equations for the three-body distribution (21 pages)	195121
Gary G. Hoffman	
Corrected local-density approximation band structures, linear-response dielectric functions, and quasiparticle lifetimes in noble metals (11 pages)	195122
V. P. Zhukov, F. Aryasetiawan, E. V. Chulkov, I. G. de Gurtubay, and P. M. Echenique	
Quantum critical point in a periodic Anderson model (9 pages)	195123
Peter van Dongen, Kingshuk Majumdar, Carey Huscroft, and Fu-Chun Zhang	
Charge redistribution and polarization energy of organic molecular crystals (12 pages)	195124
E. V. Tsiper and Z. G. Soos	
Plane-wave DFT-LDA calculation of the electronic structure and absorption spectrum of copper (9 pages)	195125
Andrea Marini, Giovanni Onida, and Rodolfo Del Sole	
Convergent recursive $O(N)$ method for <i>ab initio</i> tight-binding calculations (4 pages)	195126
T. Ozaki and K. Terakura	
Analytical results of the one-dimensional Hubbard model in the high-temperature limit (8 pages)	195127
I. C. Charret, E. V. Corrêa Silva, S. M. de Souza, O. Rojas Santos, M. T. Thomaz, and A. T. Costa, Jr.	
Lifetimes and mean-free paths of hot electrons in the alkali metals (7 pages)	195128
J. S. Dolado, V. M. Silkin, M. A. Cazalilla, A. Rubio, and P. M. Echenique	
Vacuum ultraviolet excitation and emission properties of Pr^{3+} and Ce^{3+} in MSO_4 ($M = \text{Ba}$, Sr , and Ca) and predicting quantum splitting by Pr^{3+} in oxides and fluorides (12 pages)	195129
E. van der Kolk, P. Dorenbos, A. P. Vink, R. C. Perego, C. W. E. van Eijk, and A. R. Lakshmanan	
Quantum Monte Carlo algorithm for nonlocal corrections to the dynamical mean-field approximation (23 pages)	195130
M. Jarrell, Th. Maier, C. Huscroft, and S. Moukouri	
Signatures of Wannier-Stark and surface states in electron tunneling and related phenomena: Electron transmission through a tilted band (14 pages)	195131
Alexander Onipko and Lyuba Malysheva	
Fermi-surface geometry of the $\text{Cu-27.5 at. \% Pd}$ disordered alloy and short-range order (6 pages)	195132
I. Matsumoto, H. Kawata, and N. Shiotani	
X-ray resonant scattering studies of orbital and charge ordering in $\text{Pr}_{1-x}\text{Ca}_x\text{MnO}_3$ (17 pages)	195133
M. v. Zimmermann, C. S. Nelson, J. P. Hill, Doon Gibbs, M. Blume, D. Casa, B. Keimer, Y. Murakami, C.-C. Kao, C. Venkataraman, T. Gog, Y. Tomioka, and Y. Tokura	
Efficient linearization of the augmented plane-wave method (9 pages)	195134
Georg K. H. Madsen, Peter Blaha, Karlheinz Schwarz, Elisabeth Sjöstedt, and Lars Nordström	
Semiconductors I: bulk	
Microstructure of local defects in amorphous Si:H : A quantum chemical study (11 pages)	195201
Thomas Krüger and Alexander F. Sax	
Hydrogen diffusion, complex formation, and dissociation in acceptor-doped silicon carbide (12 pages)	195202
M. S. Janson, A. Hallén, M. K. Linnarsson, and B. G. Svensson	
Effects of aggregation on the excitation transfer in perylene-end-capped polyindeno[1,2,3- <i>cd</i>]fluorene studied by time-resolved photoluminescence spectroscopy (9 pages)	195203
L. M. Herz, C. Silva, R. H. Friend, R. T. Phillips, S. Setayesh, S. Becker, D. Marsitsky, and K. Müllen	

Hydrogen passivation of beryllium in <i>p</i> -type GaAs (5 pages)	195204
C. Wang and Q.-M. Zhang	
Trapping and detrapping effects in high-quality chemical-vapor-deposition diamond films: Pulse shape analysis of diamond particle detectors (8 pages)	195205
Marco Marinelli, E. Milani, A. Paoletti, A. Tucciarone, G. Verona-Rinati, M. Angelone, and M. Pillon	
High-frequency (95 GHz) electron paramagnetic resonance study of the photoinduced charge transfer in conjugated polymer-fullerene composites (6 pages)	195206
J. De Ceuster, E. Goovaerts, A. Bouwen, J. C. Hummelen, and V. Dyakonov	
Implantation sites of In, Cd, and Hf ions in diamond (8 pages)	195207
K. Bharuth-Ram, A. Burchard, M. Deicher, H. Quintel, M. Restle, H. Hofsäss, and C. Ronning	
Controlled <i>p</i> -type doping of polycrystalline and amorphous organic layers: Self-consistent description of conductivity and field-effect mobility by a microscopic percolation model (9 pages)	195208
B. Maennig, M. Pfeiffer, A. Nollau, X. Zhou, K. Leo, and P. Simon	
Experimental evidence of condensation of electron-hole pairs at room temperature during femtosecond cooperative emission (5 pages)	195209
Peter P. Vasil'ev, H. Kan, H. Ohta, and T. Hiruma	
Binding energies of excitons trapped by ionized donors in semiconductors (9 pages)	195210
A. S. dos Santos, Mauro Masili, and J. J. De Groote	
Annealing kinetics of vacancy-related defects in low-dose MeV self-ion-implanted <i>n</i> -type silicon (10 pages)	195211
P. Pellegrino, P. L��v��que, J. Lalita, A. Hall��n, C. Jagadish, and B. G. Svensson	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Magnetoconductance fluctuations and weak localization in quantum dots: Reliability of the semiclassical approach (12 pages)	195301
T. Blomquist and I. V. Zozoulenko	
Electron-hole separation studies near the $\nu=1$ quantum Hall state in modulation-doped GaAs/(Al,Ga)As single heterojunctions in high magnetic fields (6 pages)	195302
Yongmin Kim, F. M. Munteanu, C. H. Perry, D. G. Rickel, J. A. Simmons, L. N. Pfeiffer, and K. W. West	
Theoretical description of electronic properties of vertical gated quantum dots (13 pages)	195303
S. Bednarek, B. Szafran, and J. Adamowski	
Origin of enhanced dynamic nuclear polarization and all-optical nuclear magnetic resonance in GaAs quantum wells (10 pages)	195304
G. Salis, D. D. Awschalom, Y. Ohno, and H. Ohno	
Influence of surface morphology on the Si(100) and (111) ionization potentials (7 pages)	195305
C. Sgiarovello, N. Binggeli, and A. Baldereschi	
Nucleus-mediated spin-flip transitions in GaAs quantum dots (4 pages)	195306
Sigurdur I. Erlingsson, Yuli V. Nazarov, and Vladimir I. Fal'ko	
Beyond the random phase approximation in the Singwi-Sj��lander theory of the half-filled Landau level (9 pages)	195307
J. Dietel and W. Weller	
Acoustoelectric pumping through a ballistic point contact in the presence of magnetic fields (7 pages)	195308
O. Entin-Wohlman, Y. Levinson, and P. W��lfle	
Highly confined excitons in MgS/ZnSe quantum wells grown by molecular beam epitaxy (8 pages)	195309
C. Bradford, C. B. O'Donnell, B. Urbaszek, C. Morhain, A. Balocchi, K. A. Prior, and B. C. Cavenett	
Hamiltonian theory of the fractional quantum Hall effect: Conserving approximation for incompressible fractions (17 pages)	195310
Ganpathy Murthy	

Quasibound states in type-II ZnTe/CdSe superlattices studied by modulation spectroscopies and photoconductivity at room temperature (5 pages)	195311
S. M. Tseng, Y. F. Chen, Y. T. Cheng, C. W. Hsu, Y. S. Huang, and D. Y. Lin	
Structural and electronic properties of semiconductor binary microclusters A_mB_n ($A, B = \text{Si, Ge, C}$): A B3LYP-DFT study (5 pages)	195312
Si-Dian Li, Zhi-Guang Zhao, Xiu-Feng Zhao, Hai-Shun Wu, and Zhi-Hao Jin	
Many-body effects on excitonic optical properties of photoexcited semiconductor quantum wire structures (16 pages)	195313
D. W. Wang and S. Das Sarma	
Qubit cross talk and entanglement decay (6 pages)	195314
J. S. Pratt and J. H. Eberly	
Nonlinear ac transport and local fields in quantum wires (15 pages)	195315
A. Fechner, M. Sassetti, B. Kramer, and E. Galleani d'Agliano	
Inclined inheritance of interface roughness in semiconductor superlattices as characterized by x-ray reciprocal space mapping (6 pages)	195316
M. Schmidbauer, R. Opitz, Th. Wiebach, and R. Köhler	
Homogeneous linewidths and confined-phonon sidebands of the resonant exciton luminescence of CuCl quantum dots (5 pages)	195317
K. Edamatsu, T. Itoh, K. Matsuda, and S. Saikan	
Experimental and theoretical investigation of interband and intersubband transitions in type-II InAs/AlSb superlattices (6 pages)	195318
I. Prevot, B. Vinter, F. H. Julien, F. Fossard, and X. Marcadet	
Spin filtering and magnetoresistance in ballistic tunnel junctions (5 pages)	195319
J. C. Egues, C. Gould, G. Richter, and L. W. Molenkamp	
Storage qubits and their potential implementation through a semiconductor double quantum dot (7 pages)	195320
Ehoud Pazy, Irene D'Amico, Paolo Zanardi, and Fausto Rossi	
Strong anti-Stokes photoluminescence of GaAs free excitons in GaAs/Ga _{1-x} Al _x As heterojunctions (5 pages)	195321
J. X. Shen, R. Pittini, and Y. Oka	
Effects of interwell coupling on plasmon modes in symmetric double square quantum well structures (9 pages)	195322
Xin-Hai Liu, Xue-Hua Wang, and Ben-Yuan Gu	
Two interacting electrons in a vertical quantum dot with magnetic fields (6 pages)	195323
J. T. Lin and T. F. Jiang	
Tip-induced local anodic oxidation on the native SiO ₂ layer of Si(111) using an atomic force microscope (5 pages)	195324
Y.-R. Ma, C. Yu, Y.-D. Yao, Y. Liou, and S.-F. Lee	
Optical studies of strain effects in quantum wells grown on (311) and (100) GaAs substrates (6 pages)	195325
S. L. S. Freire, J. E. T. Reis, L. A. Cury, F. M. Matinaga, J. F. Sampaio, and F. E. G. Guimarães	
Optical spectroscopy of charged excitons in single quantum dot photodiodes (5 pages)	195326
M. Baier, F. Findeis, A. Zrenner, M. Bichler, and G. Abstreiter	
Single-particle path integral for composite fermions and the renormalization of the effective mass (22 pages)	195327
Kasper Astrup Eriksen, Per Hedegård, and Henrik Bruus	
<i>Ab initio</i> study of the Bi-covered GaAs(111)B surface (7 pages)	195328
R. H. Miwa and G. P. Srivastava	
Misfit relaxation of the AlN/Al ₂ O ₃ (0001) interface (6 pages)	195329
Th. Kehagias, Ph. Komninou, G. Nouet, P. Ruterana, and Th. Karakostas	
Electron confinement and optical enhancement in Si/SiO ₂ superlattices (7 pages)	195330
Pierre Carrier, Laurent J. Lewis, and M. W. C. Dharma-wardana	

Field-induced transient hole transport in an $\text{Al}_{0.3}\text{Ga}_{0.7}\text{As}$ -based p - i - n nanostructure studied by picosecond Raman spectroscopy (7 pages)	195331
Y. Chen, K. T. Tsen, O. F. Sankey, and D. K. Ferry	
Space-charge limited current in the single-electron regime (14 pages)	195332
Matthias W. Klein, David H. Dunlap, and George G. Malliaras	
Resonant photoelectromagnetic effect in semiconductors (10 pages)	195333
Tomonori Okashita, Hiromi Kobori, and Tyuzi Ohyama	
Umklapp electron-electron scattering in weakly modulated two-dimensional electron systems (15 pages)	195334
Seiji Uryu and Tsuneya Ando	
Bound polaron in a spherical quantum dot: The all-coupling variational approach (12 pages)	195335
Dmitriy V. Melnikov and W. Beall Fowler	
Hall coefficient and electron-electron interaction of two-dimensional electrons in Si MOSFETs (5 pages)	195336
Sergey A. Vitkalov	

Surface physics, low-dimensional systems, and related topics

Orientationally ordered island growth of higher fullerenes on $\text{Ag/Si}(111)-(\sqrt{3}\times\sqrt{3})R30^\circ$ (6 pages)	195401
M. J. Butcher, J. W. Nolan, M. R. C. Hunt, P. H. Beton, L. Dunsch, P. Kuran, P. Georgi, and T. J. S. Dennis	
Renormalized molecular levels in a $\text{Sc}_3\text{N@C}_{80}$ molecular electronic device (5 pages)	195402
Brian Larade, Jeremy Taylor, Q. R. Zheng, Hatem Mehrez, Pawel Pomorski, and Hong Guo	
Intrinsic and H-induced defects at Si-SiO ₂ interfaces (6 pages)	195403
D. J. Chadi	
Electronic properties of carbon nanotubes by transmission electron energy-loss spectroscopy (13 pages)	195404
B. W. Reed and M. Sarikaya	
Surface embedded atom model of the electrolyte-metal interface (7 pages)	195405
Michael I. Haftel and Mervine Rosen	
Surfactant effect of gallium during molecular-beam epitaxy of GaN on AlN (0001) (12 pages)	195406
Guido Mula, C. Adelmann, S. Moehl, J. Oullier, and B. Daudin	
Single-particle and collective excitations of a two-dimensional electron gas at the Cs/InAs(110) surface (5 pages)	195407
R. Biagi, Valdis Corradini, G. Bertoni, Carlo Mariani, U. del Pennino, and Maria Grazia Betti	
Azobenzene polymer surface deformation due to the gradient force of the optical near field of monodispersed polystyrene spheres (5 pages)	195408
Taiji Ikawa, Takuya Mitsuka, Makoto Hasegawa, Masaaki Tsuchimori, Osamu Watanabe, and Yoshimasa Kawata	
Empirical potential description of energetics and thermodynamic properties in expanded-volume silicon clathrates (15 pages)	195409
Koji Moriguchi, Shinji Munetoh, Akira Shintani, and Teruaki Motooka	
Collective excitations in alkali metals on Al(111) (13 pages)	195410
S. R. Barman, C. Stampfl, P. Häberle, W. Ibañez, Y. Q. Cai, and K. Horn	
Fermi surfaces of the two-dimensional surface states on vicinal Cu(111) (8 pages)	195411
F. Baumberger, T. Greber, and J. Osterwalder	
Multiwalled carbon nanotube: Luttinger versus Fermi liquid (4 pages)	195412
R. Tarkiainen, M. Ahlskog, J. Penttilä, L. Roschier, P. Hakonen, M. Paalanen, and E. Sonin	
Orientational dependence of current through molecular films (4 pages)	195413
P. E. Kornilovitch and A. M. Bratkovsky	
Density-functional calculation of van der Waals forces for free-electron-like surfaces (7 pages)	195414
Erika Hult, Per Hyldgaard, Jan Rossmeisl, and Bengt I. Lundqvist	

CONTENTS - *Continued*

PHYSICAL REVIEW B

THIRD SERIES, VOLUME 64, NUMBER 19

15 NOVEMBER 2001-I

Oscillation of the optical second-harmonic generation intensity during Ag thin film growth on a Si(111)7×7 surface (5 pages)	195415
H. Hirayama, T. Kawata, and K. Takayanagi	
Phonon eigenvectors of chiral nanotubes (7 pages)	195416
S. Reich, C. Thomsen, and P. Ordejón	
Measurements of the population partitions and state-selected flight-time distributions of keV ion-beam-sputtered metastable atoms (12 pages)	195417
E. Vandeweert, P. Lievens, V. Philippsen, J. Bastiaansen, and R. E. Silverans	
Structural transitions of perylene and coronene on silver and gold surfaces: A molecular-beam epitaxy LEED study (10 pages)	195418
C. Seidel, R. Ellerbrake, L. Gross, and H. Fuchs	
Structural and electronic properties of carbon nanotube tapers (7 pages)	195419
V. Meunier, M. Buongiorno Nardelli, C. Roland, and J. Bernholc	
Structure of aluminum atomic chains (6 pages)	195420
Prasenjit Sen, S. Ciraci, A. Buldum, and Inder P. Batra	

ERRATA

Erratum: Electrostatic screening near semiconductor surfaces [Phys. Rev. B 61 , 13 821 (2000)] (1 page)	199901(E)
Maja Krčmar, Wayne M. Saslow, and Michael B. Weimer	
Erratum: First-principles study of the adsorption of C ₂ H ₂ and C ₂ H ₄ on Si(001) [Phys. Rev. B 63 , 073306 (2001)] (1 page)	199902(E)
Jun-Hyung Cho, Leonard Kleinman, C. T. Chan, and Kwang S. Kim	

Cumulative Author Index	iii
-------------------------------	-----